Product Name Document Number		BM153 FHY-WD-08-01-048		Product Category Bluetooth Module Release date 2010-5-6		Page Published department		Page 1 of 1		
								R & D	Revision	V9.0
No.	No. Component Number		Vendor part numbers	Component specifications describe		Package	The amount	Component locations	Manufacturer	Price
	Integrate cir	rcuit				ı		· I		
1	EI0-C57E687CG12		BC57E687C-GITB-E4	BC05 Multimedia External		LFBGA	1	U1	CSR	
2	EI0-SS	T39VF1602	SST39VF1601-90-4C-B3KE	Flash Memory		48-ball FBGA	1	U2		
	EI0-T39VF160102		SST39VF1601-70-4C-B3KE	Flash Memory		48-ball FBGA				
	EI0-X29LV160CB2		MX29LV160CBXBC-70G	Flash Memory		48-ball FBGA				
	EI0-6D90BF10202		S29AL016D90BFI02	Flash Memory		48-ball FBGA				
	EI0-S29AL016J02		S29AL016J70BFI020	Flash Memory		48-ball FBGA				
	RF					•				
3	EA0-BL	.201205K20	BL2012-05K2450	SMD Balun		2012	1	T1		
	EA0-CB	A47117140	CBA4711714002454K	SMD Balun		2012				
4	EA0-BF	2012F2R40	BF2012-F2R4DAATKF	Bandpass filter		2012	1	F1		
	EA0-CFL41117140		CFL4111714032454K	Bandpass filter		2012				
	Capacito	r								
5	ECS-04022P20GCC			Ceramic Capacito	r(COG) 2p2 ±0.25pF 50V	0402	2	C15,C16		
6	ECS-040206P8GC0			Ceramic Capacitor(COG) 6.8p ±0.25% 50V		0402	1	C10		
7	ECS-0402045PGJC			Ceramic Capacitor(COG) 15p ±5% 50V		0402	2	C6,C17		
8	ECS-0402018PGJ0			Ceramic Capacitor(COG) 18p ±5% 50V		0402	1	C11		
9	ECS-0402010NGKX			Ceramic Capacitor(X7R) 10n ±10% 50V		0402	4	C4,C5,C8,C14		
10	ECS-0402022NDK0			Ceramic Capacit	or(X7R) 22n ±10% 50V	0402	1	C12		
11	ECS-0402047NGK0			Ceramic Capacitor(X7R) 47n ±10% 50V		0402	1	C13		
12	ECS-06032U20AZ0			Ceramic Capacitor	(X5R) 2u2 +80,-20% 6.3V	0603	4	C2,7,C9,C18		
13	ECS-0805010UBZ0			Ceramic Capacitor	(X5R) 10u +80,-20% 6.3V	0805	1	C3		
	Resistor	•								
14	ERS-04022R200J0			Thick Film	Resistor 2R2 ±5%	0402	3	R1,R2,R3		
	Inductor	r								
15	ELS-08	06022U0K0		Thick Film	Inductor 22u ±10%	0806	1	L1		
16	ELS-04	0203N30F0		Thick Film	Inductor 3.3n ±0.1	0402	2	L2, L3		
17	ELS-04	ELS-0402022N0J0		Thick Film Inductor 22n ±5%		0402	1	L4		
	Crystal									
18		02D526000	TN4-25886	-	al 26MHz ±10ppm	3*2.5	1	Y1		
19		02D526000	7M26000056	· ·	26MHz ±10ppm 9pF	3.2*2.5mm				
20	EJ0-3D	02D526001	HSX321S	SMD Crystal	26MHz ±10ppm 9pF	3.2*2.5mm				
	PCB									
21	EPB-BM1	50V2D0000	PCB-BM150-V2.0	FR4 Four-lay	ver board FR4:0.6mm		1			